

# LM2727/LM2737 N-Channel FET Synchronous Buck Regulator Controller for Low Output Voltages

Check for Samples: [LM2727](#), [LM2737](#)

## FEATURES

- Input Power from 2.2V to 16V
- Output Voltage Adjustable Down to 0.6V
- Power Good flag, Adjustable Soft-Start and Output Enable for Easy Power Sequencing
- Output Over-Voltage and Under-Voltage Latch-Off (LM2727)
- Output Over-Voltage and Under-Voltage Flag (LM2737)
- Reference Accuracy: 1.5% (0°C - 125°C)
- Current Limit Without Sense Resistor
- Soft Start
- Switching Frequency from 50 kHz to 2 MHz
- TSSOP-14 Package

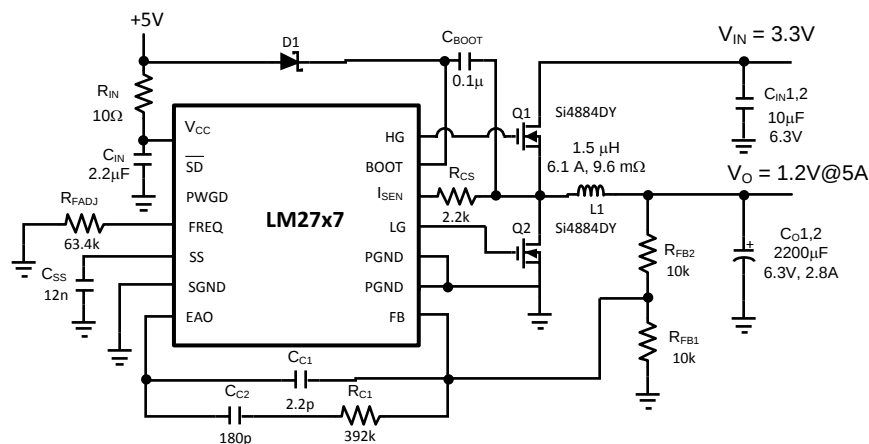
## APPLICATIONS

- Cable Modems
- Set-Top Boxes/ Home Gateways
- DDR Core Power
- High-Efficiency Distributed Power
- Local Regulation of Core Power

## DESCRIPTION

The LM2727 and LM2737 are high-speed, synchronous, switching regulator controllers. They are intended to control currents of 0.7A to 20A with up to 95% conversion efficiencies. The LM2727 employs output over-voltage and under-voltage latch-off. For applications where latch-off is not desired, the LM2737 can be used. Power up and down sequencing is achieved with the power-good flag, adjustable soft-start and output enable features. The LM2727 and LM2737 operate from a low-current 5V bias and can convert from a 2.2V to 16V power rail. Both parts utilize a fixed-frequency, voltage-mode, PWM control architecture and the switching frequency is adjustable from 50kHz to 2MHz by adjusting the value of an external resistor. Current limit is achieved by monitoring the voltage drop across the on-resistance of the low-side MOSFET, which enhances low duty-cycle operation. The wide range of operating frequencies gives the power supply designer the flexibility to fine-tune component size, cost, noise and efficiency. The adaptive, non-overlapping MOSFET gate-drivers and high-side bootstrap structure helps to further maximize efficiency. The high-side power FET drain voltage can be from 2.2V to 16V and the output voltage is adjustable down to 0.6V.

## Typical Application



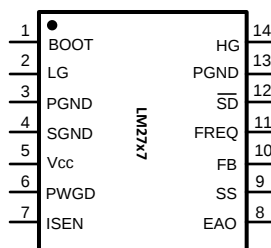
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## Connection Diagram



**Figure 1. 14-Lead Plastic TSSOP**  
 $\theta_{JA} = 155^{\circ}\text{C/W}$   
 See Package Number PW0014A

### PIN DESCRIPTION

|                                                                                                                                                                                                                                                                |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>BOOT (Pin 1)</b> - Supply rail for the N-channel MOSFET gate drive. The voltage should be at least one gate threshold above the regulator input voltage to properly turn on the high-side N-FET.                                                            |
| <b>LG (Pin 2)</b> - Gate drive for the low-side N-channel MOSFET. This signal is interlocked with HG to avoid shoot-through problems.                                                                                                                          |
| <b>PGND (Pins 3, 13)</b> - Ground for FET drive circuitry. It should be connected to system ground.                                                                                                                                                            |
| <b>SGND (Pin 4)</b> - Ground for signal level circuitry. It should be connected to system ground.                                                                                                                                                              |
| <b>V<sub>CC</sub> (Pin 5)</b> - Supply rail for the controller.                                                                                                                                                                                                |
| <b>PWGD (Pin 6)</b> - Power Good. This is an open drain output. The pin is pulled low when the chip is in UVP, OVP, or UVLO mode. During normal operation, this pin is connected to V <sub>CC</sub> or other voltage source through a pull-up resistor.        |
| <b>ISEN (Pin 7)</b> - Current limit threshold setting. This sources a fixed 50μA current. A resistor of appropriate value should be connected between this pin and the drain of the low-side FET.                                                              |
| <b>EAO (Pin 8)</b> - Output of the error amplifier. The voltage level on this pin is compared with an internally generated ramp signal to determine the duty cycle. This pin is necessary for compensating the control loop.                                   |
| <b>SS (Pin 9)</b> - Soft start pin. A capacitor connected between this pin and ground sets the speed at which the output voltage ramps up. Larger capacitor value results in slower output voltage ramp but also lower inrush current.                         |
| <b>FB (Pin 10)</b> - This is the inverting input of the error amplifier, which is used for sensing the output voltage and compensating the control loop.                                                                                                       |
| <b>FREQ (Pin 11)</b> - The switching frequency is set by connecting a resistor between this pin and ground.                                                                                                                                                    |
| <b>SD (Pin 12)</b> - IC Logic Shutdown. When this pin is pulled low the chip turns off the high side switch and turns on the low side switch. While this pin is low, the IC will not start up. An internal 20μA pull-up connects this pin to V <sub>CC</sub> . |
| <b>HG (Pin 14)</b> - Gate drive for the high-side N-channel MOSFET. This signal is interlocked with LG to avoid shoot-through problems.                                                                                                                        |



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings<sup>(1)(2)</sup>

|                                     |                |
|-------------------------------------|----------------|
| V <sub>CC</sub>                     | 7V             |
| BOOTV                               | 21V            |
| Junction Temperature                | 150°C          |
| Storage Temperature                 | –65°C to 150°C |
| Soldering Information               |                |
| Lead Temperature (soldering, 10sec) | 260°C          |
| Infrared or Convection (20sec)      | 235°C          |
| ESD Rating <sup>(3)</sup>           | 2 kV           |

- (1) Absolute maximum ratings indicate limits beyond which damage to the device may occur. **Operating ratings** indicate conditions for which the device operates correctly. **Operating Ratings** do not imply ensured performance limits.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) The human body model is a 100pF capacitor discharged through a 1.5k resistor into each pin.

## Operating Ratings

|                                       |                 |
|---------------------------------------|-----------------|
| Supply Voltage (V <sub>CC</sub> )     | 4.5V to 5.5V    |
| Junction Temperature Range            | –40°C to +125°C |
| Thermal Resistance (θ <sub>JA</sub> ) | 155°C/W         |

## Electrical Characteristics

V<sub>CC</sub> = 5V unless otherwise indicated. Typicals and limits appearing in plain type apply for T<sub>A</sub>=T<sub>J</sub>=+25°C. Limits appearing in boldface type apply over full Operating Temperature Range. Datasheet min/max specification limits are ensured by design, test, or statistical analysis.

| Symbol              | Parameter                                      | Conditions                                            | Min                    | Typ        | Max                    | Units |
|---------------------|------------------------------------------------|-------------------------------------------------------|------------------------|------------|------------------------|-------|
| V <sub>FB_ADJ</sub> | FB Pin Voltage                                 | V <sub>CC</sub> = 4.5V, 0°C to +125°C                 | <b>0.591</b>           | 0.6        | <b>0.609</b>           | V     |
|                     |                                                | V <sub>CC</sub> = 5V, 0°C to +125°C                   | <b>0.591</b>           | 0.6        | <b>0.609</b>           |       |
|                     |                                                | V <sub>CC</sub> = 5.5V, 0°C to +125°C                 | <b>0.591</b>           | 0.6        | <b>0.609</b>           |       |
|                     |                                                | V <sub>CC</sub> = 4.5V, –40°C to +125°C               | <b>0.589</b>           | 0.6        | <b>0.609</b>           |       |
|                     |                                                | V <sub>CC</sub> = 5V, –40°C to +125°C                 | <b>0.589</b>           | 0.6        | <b>0.609</b>           |       |
|                     |                                                | V <sub>CC</sub> = 5.5V, –40°C to +125°C               | <b>0.589</b>           | 0.6        | <b>0.609</b>           |       |
| V <sub>ON</sub>     | UVLO Thresholds                                | Rising<br>Falling                                     |                        | 4.2<br>3.6 |                        | V     |
| I <sub>Q-V5</sub>   | Operating V <sub>CC</sub> Current              | SD = 5V, FB = 0.55V<br>Fsw = 600kHz                   | <b>1</b>               | 1.5        | <b>2</b>               | mA    |
|                     |                                                | SD = 5V, FB = 0.65V<br>Fsw = 600kHz                   | <b>0.8</b>             | 1.7        | <b>2.2</b>             |       |
|                     | Shutdown V <sub>CC</sub> Current               | SD = 0V                                               | <b>0.15</b>            | 0.4        | <b>0.7</b>             | mA    |
| t <sub>PWGD1</sub>  | PWGD Pin Response Time                         | FB Voltage Going Up                                   |                        | 6          |                        | μs    |
| t <sub>PWGD2</sub>  | PWGD Pin Response Time                         | FB Voltage Going Down                                 |                        | 6          |                        | μs    |
| I <sub>SD</sub>     | SD Pin Internal Pull-up Current                |                                                       |                        | 20         |                        | μA    |
| I <sub>SS-ON</sub>  | SS Pin Source Current                          | SS Voltage = 2.5V<br>0°C to +125°C<br>–40°C to +125°C | <b>8</b><br><b>5</b>   | 11<br>11   | <b>15</b><br><b>15</b> | μA    |
| I <sub>SS-OC</sub>  | SS Pin Sink Current During Over Current        | SS Voltage = 2.5V                                     |                        | 95         |                        | μA    |
| I <sub>SEN-TH</sub> | I <sub>SEN</sub> Pin Source Current Trip Point | 0°C to +125°C<br>–40°C to +125°C                      | <b>35</b><br><b>28</b> | 50<br>50   | <b>65</b><br><b>65</b> | μA    |

## Electrical Characteristics (continued)

$V_{CC} = 5V$  unless otherwise indicated. Typical and limits appearing in plain type apply for  $T_A = T_J = +25^\circ C$ . Limits appearing in boldface type apply over full Operating Temperature Range. Datasheet min/max specification limits are ensured by design, test, or statistical analysis.

| Symbol                          | Parameter                                 | Conditions                                                   | Min                          | Typ            | Max                          | Units      |
|---------------------------------|-------------------------------------------|--------------------------------------------------------------|------------------------------|----------------|------------------------------|------------|
| <b>ERROR AMPLIFIER</b>          |                                           |                                                              |                              |                |                              |            |
| GBW                             | Error Amplifier Unity Gain Bandwidth      |                                                              |                              | 5              |                              | MHz        |
| G                               | Error Amplifier DC Gain                   |                                                              |                              | 60             |                              | dB         |
| SR                              | Error Amplifier Slew Rate                 |                                                              |                              | 6              |                              | V/ $\mu$ A |
| $I_{FB}$                        | FB Pin Bias Current                       | FB = 0.55V<br>FB = 0.65V                                     | <b>0</b><br><b>0</b>         | 15<br>30       | <b>100</b><br><b>155</b>     | nA         |
| $I_{EAO}$                       | EAO Pin Current Sourcing and Sinking      | $V_{EAO} = 2.5$ , FB = 0.55V<br>$V_{EAO} = 2.5$ , FB = 0.65V |                              | 2.8<br>0.8     |                              | mA         |
| $V_{EA}$                        | Error Amplifier Maximum Swing             | Minimum<br>Maximum                                           |                              | 1.2<br>3.2     |                              | V          |
| <b>GATE DRIVE</b>               |                                           |                                                              |                              |                |                              |            |
| $I_{Q-BOOT}$                    | BOOT Pin Quiescent Current                | BOOTV = 12V, EN = 0<br>0°C to +125°C<br>-40°C to +125°C      |                              | 95<br>95       | <b>160</b><br><b>215</b>     | $\mu$ A    |
| $R_{DS1}$                       | Top FET Driver Pull-Up ON resistance      | BOOT-SW = 5V@350mA                                           |                              | 3              |                              | $\Omega$   |
| $R_{DS2}$                       | Top FET Driver Pull-Down ON resistance    | BOOT-SW = 5V@350mA                                           |                              | 2              |                              | $\Omega$   |
| $R_{DS3}$                       | Bottom FET Driver Pull-Up ON resistance   | BOOT-SW = 5V@350mA                                           |                              | 3              |                              | $\Omega$   |
| $R_{DS4}$                       | Bottom FET Driver Pull-Down ON resistance | BOOT-SW = 5V@350mA                                           |                              | 2              |                              | $\Omega$   |
| <b>OSCILLATOR</b>               |                                           |                                                              |                              |                |                              |            |
| $f_{OSC}$                       | PWM Frequency                             | $R_{FADJ} = 590k\Omega$                                      |                              | 50             |                              | kHz        |
|                                 |                                           | $R_{FADJ} = 88.7k\Omega$                                     |                              | 300            |                              |            |
|                                 |                                           | $R_{FADJ} = 42.2k\Omega$ , 0°C to +125°C                     | <b>500</b>                   | 600            | <b>700</b>                   |            |
|                                 |                                           | $R_{FADJ} = 42.2k\Omega$ , -40°C to +125°C                   | <b>490</b>                   | 600            | <b>700</b>                   |            |
|                                 |                                           | $R_{FADJ} = 17.4k\Omega$                                     |                              | 1400           |                              |            |
|                                 |                                           | $R_{FADJ} = 11.3k\Omega$                                     |                              | 2000           |                              |            |
| D                               | Max Duty Cycle                            | $f_{PWM} = 300kHz$<br>$f_{PWM} = 600kHz$                     |                              | 90<br>88       |                              | %          |
| <b>LOGIC INPUTS AND OUTPUTS</b> |                                           |                                                              |                              |                |                              |            |
| $V_{SD-IH}$                     | SD Pin Logic High Trip Point              |                                                              |                              | 2.6            | <b>3.5</b>                   | V          |
| $V_{SD-IL}$                     | SD Pin Logic Low Trip Point               | 0°C to +125°C<br>-40°C to +125°C                             | <b>1.3</b><br><b>1.25</b>    | 1.6<br>1.6     |                              | V          |
| $V_{PWGD-TH-LO}$                | PWGD Pin Trip Points                      | FB Voltage Going Down<br>0°C to +125°C<br>-40°C to +125°C    | <b>0.413</b><br><b>0.410</b> | 0.430<br>0.430 | <b>0.446</b><br><b>0.446</b> | V          |
| $V_{PWGD-TH-HI}$                | PWGD Pin Trip Points                      | FB Voltage Going Up<br>0°C to +125°C<br>-40°C to +125°C      | <b>0.691</b><br><b>0.688</b> | 0.710<br>0.710 | <b>0.734</b><br><b>0.734</b> | V          |
| $V_{PWGD-HYS}$                  | PWGD Hysteresis (LM2737 only)             | FB Voltage Going Down FB Voltage Going Up                    |                              | 35<br>110      |                              | mV         |

## Typical Performance Characteristics

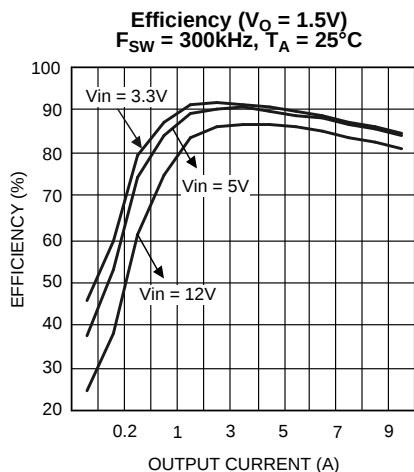


Figure 2.

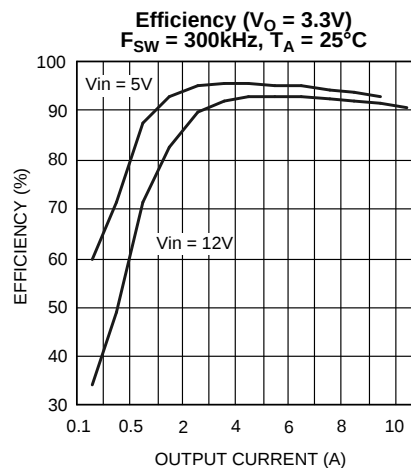


Figure 3.

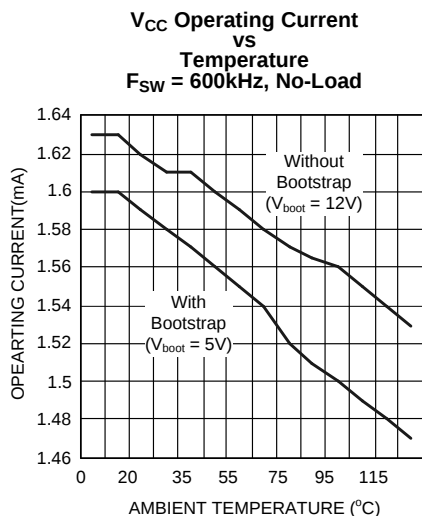


Figure 4.

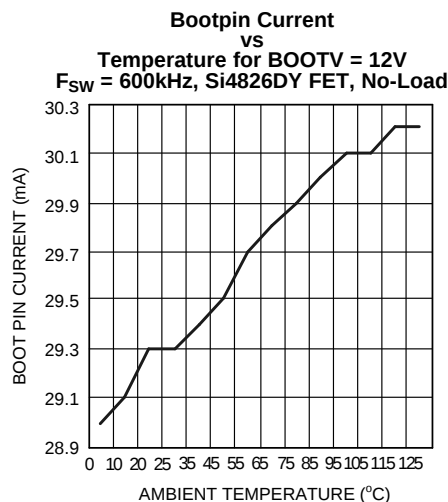


Figure 5.

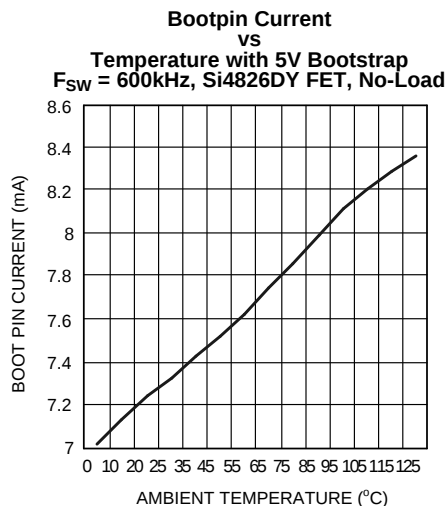


Figure 6.

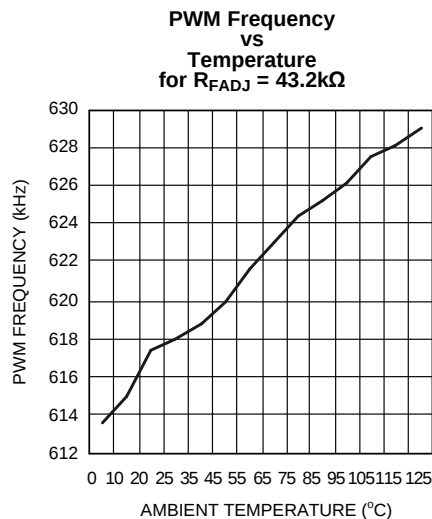


Figure 7.

### Typical Performance Characteristics (continued)

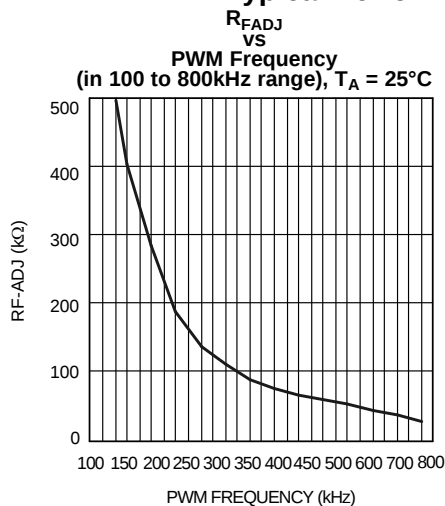


Figure 8.

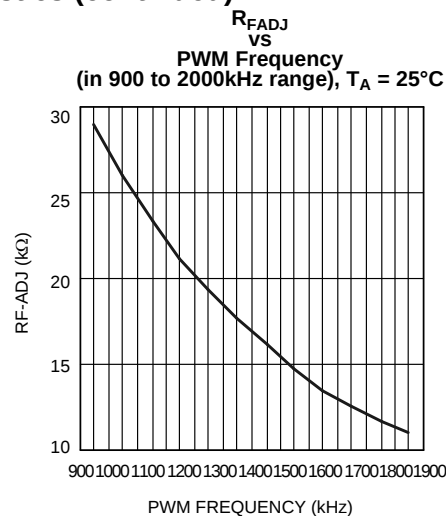


Figure 9.

**$V_{CC}$  Operating Current Plus Boot Current vs PWM Frequency** (Si4826DY FET,  $T_A = 25^\circ\text{C}$ )

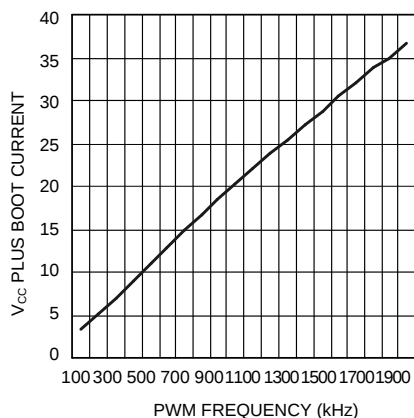


Figure 10.

**Switch Waveforms (HG Falling)**

$V_{IN} = 5\text{V}$ ,  $V_O = 1.8\text{V}$   
 $I_O = 3\text{A}$ ,  $C_{SS} = 10\text{nF}$   
 $F_{SW} = 600\text{kHz}$

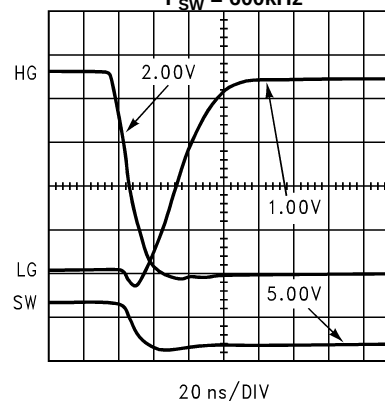


Figure 11.

**Switch Waveforms (HG Rising)**

$V_{IN} = 5\text{V}$ ,  $V_O = 1.8\text{V}$   
 $I_O = 3\text{A}$ ,  $F_{SW} = 600\text{kHz}$

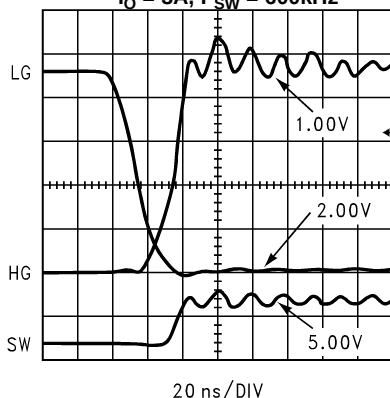


Figure 12.

**Start-Up (No-Load)**

$V_{IN} = 10\text{V}$ ,  $V_O = 1.2\text{V}$   
 $C_{SS} = 10\text{nF}$ ,  $F_{SW} = 300\text{kHz}$

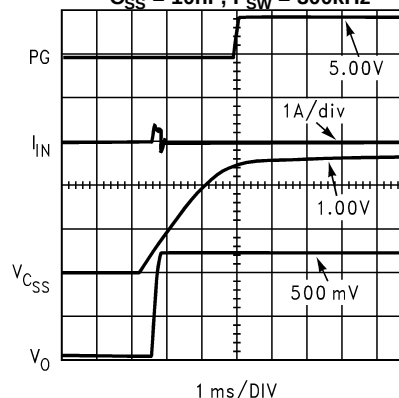
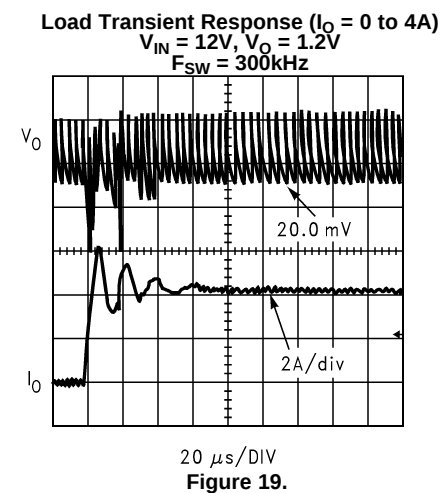
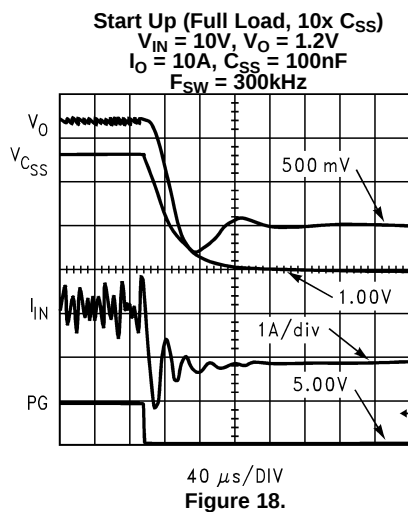
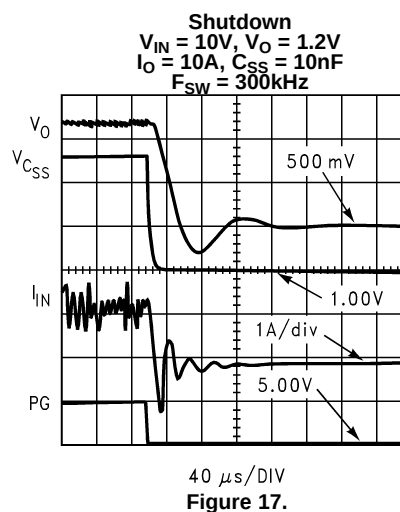
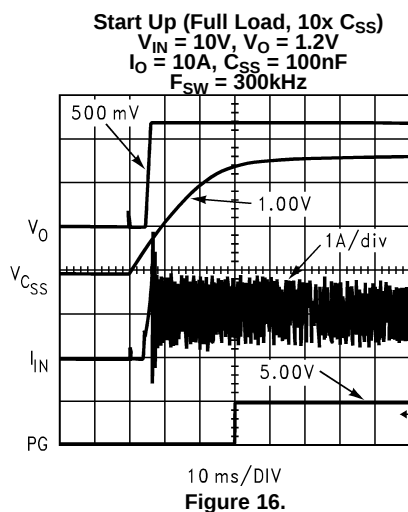
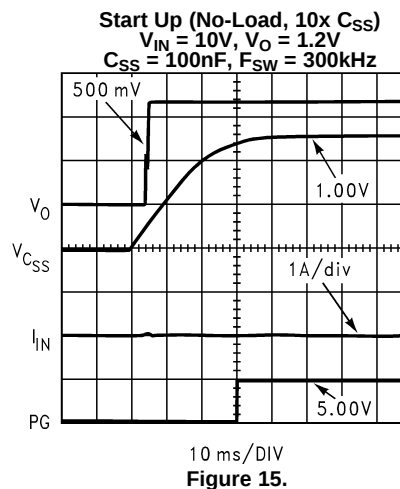
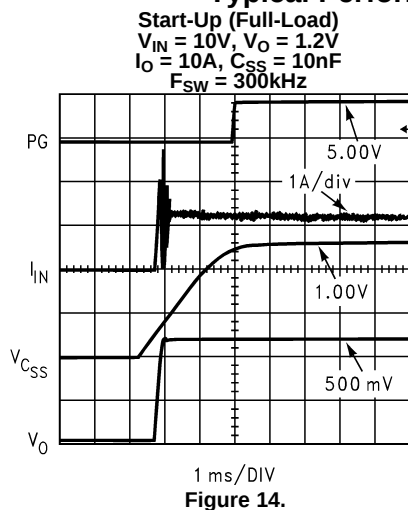


Figure 13.

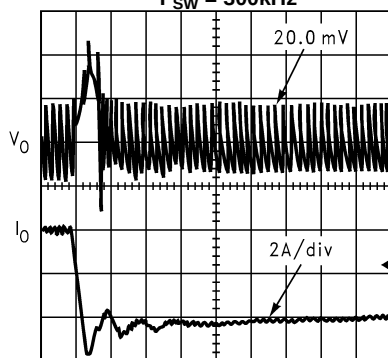
## Typical Performance Characteristics (continued)



### Typical Performance Characteristics (continued)

Load Transient Response ( $I_O = 4$  to  $0$  A)

$V_{IN} = 12$  V,  $V_O = 1.2$  V  
 $F_{SW} = 300$  kHz

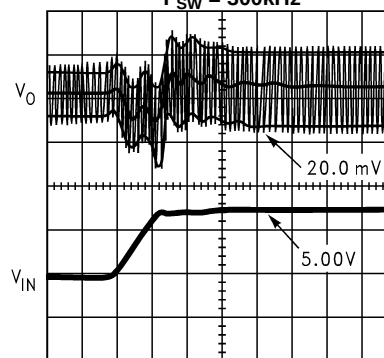


20  $\mu$ s/DIV

Figure 20.

Line Transient Response ( $V_{IN} = 5$  V to  $12$  V)

$V_O = 1.2$  V,  $I_O = 5$  A  
 $F_{SW} = 300$  kHz

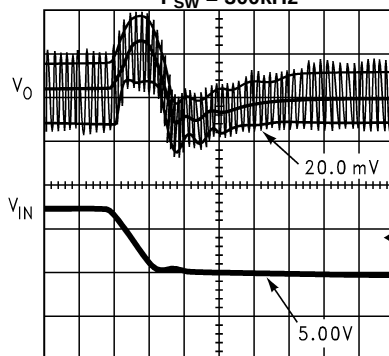


40  $\mu$ s/DIV

Figure 21.

Line Transient Response ( $V_{IN} = 12$  V to  $5$  V)

$V_O = 1.2$  V,  $I_O = 5$  A  
 $F_{SW} = 300$  kHz

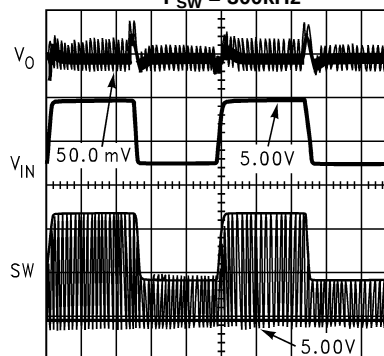


40  $\mu$ s/DIV

Figure 22.

Line Transient Response

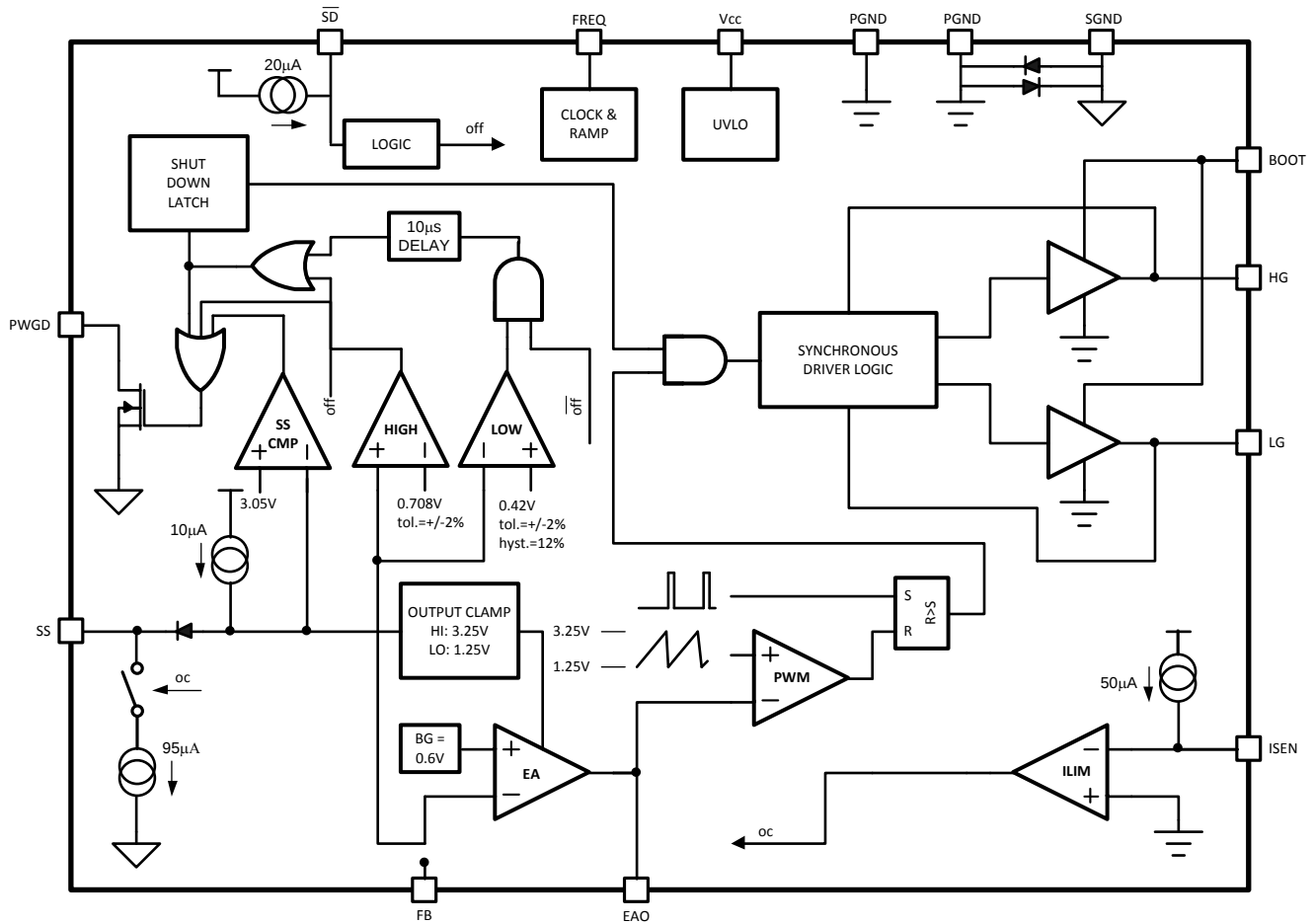
$V_O = 1.2$  V,  $I_O = 5$  A  
 $F_{SW} = 300$  kHz



400  $\mu$ s/DIV

Figure 23.

## Block Diagram



## APPLICATION INFORMATION

### THEORY OF OPERATION

The LM2727 is a voltage-mode, high-speed synchronous buck regulator with a PWM control scheme. It is designed for use in set-top boxes, thin clients, DSL/Cable modems, and other applications that require high efficiency buck converters. It has power good (PWRGD), output shutdown (SD), over voltage protection (OVP) and under voltage protection (UVP). The over-voltage and under-voltage signals are OR gated to drive the Power Good signal and a shutdown latch, which turns off the high side gate and turns on the low side gate if pulled low. Current limit is achieved by sensing the voltage  $V_{DS}$  across the low side FET. During current limit the high side gate is turned off and the low side gate turned on. The soft start capacitor is discharged by a 95 $\mu$ A source (reducing the maximum duty cycle) until the current is under control. The LM2737 does not latch off during UVP or OVP, and uses the HIGH and LOW comparators for the powergood function only.

### START UP

When  $V_{CC}$  exceeds 4.2V and the enable pin EN sees a logic high the soft start capacitor begins charging through an internal fixed 10 $\mu$ A source. During this time the output of the error amplifier is allowed to rise with the voltage of the soft start capacitor. This capacitor,  $C_{SS}$ , determines soft start time, and can be determined approximately by:

$$C_{SS} = \frac{t_{ss}}{2.5 \times 10^5} \quad (1)$$

An application for a microprocessor might need a delay of 3ms, in which case  $C_{SS}$  would be 12nF. For a different device, a 100ms delay might be more appropriate, in which case  $C_{SS}$  would be 400nF. (390 10%) During soft start the PWRGD flag is forced low and is released when the voltage reaches a set value. At this point this chip enters normal operation mode, the Power Good flag is released, and the OVP and UVP functions begin to monitor  $V_o$ .

### NORMAL OPERATION

While in normal operation mode, the LM2727/37 regulates the output voltage by controlling the duty cycle of the high side and low side FETs. The equation governing output voltage is:

$$0.6 = \frac{R_{FB1}}{R_{FB1} + R_{FB2}} V_o \quad (2)$$

The PWM frequency is adjustable between 50kHz and 2MHz and is set by an external resistor,  $R_{FADJ}$ , between the FREQ pin and ground. The resistance needed for a desired frequency is approximately:

$$R_{FADJ} = \left( \frac{20500}{\text{freq[kHz]}} \right)^{1.0526} \text{ k}\Omega \quad (3)$$

### MOSFET GATE DRIVERS

The LM2727/37 has two gate drivers designed for driving N-channel MOSFETs in a synchronous mode. Power for the drivers is supplied through the BOOTV pin. For the high side gate (HG) to fully turn on the top FET, the BOOTV voltage must be at least one  $V_{GS(th)}$  greater than  $V_{in}$ . ( $\text{BOOTV} \geq 2 \cdot V_{in}$ ) This voltage can be supplied by a separate, higher voltage source, or supplied from a local charge pump structure. In a system such as a desktop computer, both 5V and 12V are usually available. Hence if  $V_{in}$  was 5V, the 12V supply could be used for BOOTV. 12V is more than  $2 \cdot V_{in}$ , so the HG would operate correctly. For a BOOTV of 12V, the initial gate charging current is 2A, and the initial gate discharging current is typically 6A.

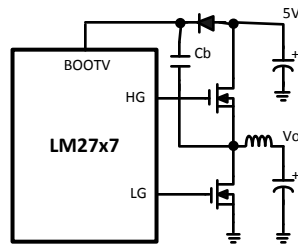


Figure 24. BOOTV Supplied by Charge Pump

In a system without a separate, higher voltage, a charge pump (bootstrap) can be built using a diode and small capacitor, Figure 24. The capacitor serves to maintain enough voltage between the top FET gate and source to control the device even when the top FET is on and its source has risen up to the input voltage level.

The LM2727/37 gate drivers use a BiCMOS design. Unlike some other bipolar control ICs, the gate drivers have rail-to-rail swing, ensuring no spurious turn-on due to capacitive coupling.

## POWER GOOD SIGNAL

The power good signal is the or-gated flag representing over-voltage and under-voltage protection. If the output voltage is 18% over its nominal value,  $V_{FB} = 0.7V$ , or falls 30% below that value,  $V_{FB} = 0.41V$ , the power good flag goes low. The converter then turns off the high side gate, and turns on the low side gate. Unlike the output (LM2727 only) the power good flag is not latched off. It will return to a logic high whenever the feedback pin voltage is between 70% and 118% of 0.6V.

## UVLO

The 4.2V turn-on threshold on  $V_{CC}$  has a built in hysteresis of 0.6V. Therefore, if  $V_{CC}$  drops below 3.6V, the chip enters UVLO mode. UVLO consists of turning off the top FET, turning on the bottom FET, and remaining in that condition until  $V_{CC}$  rises above 4.2V. As with shutdown, the soft start capacitor is discharged through a FET, ensuring that the next start-up will be smooth.

## CURRENT LIMIT

Current limit is realized by sensing the voltage across the low side FET while it is on. The  $R_{DS(on)}$  of the FET is a known value, hence the current through the FET can be determined as:

$$V_{DS} = I * R_{DS(on)} \quad (4)$$

The current limit is determined by an external resistor,  $R_{CS}$ , connected between the switch node and the ISEN pin. A constant current of 50 $\mu A$  is forced through  $R_{CS}$ , causing a fixed voltage drop. This fixed voltage is compared against  $V_{DS}$  and if the latter is higher, the current limit of the chip has been reached.  $R_{CS}$  can be found by using the following:

$$R_{CS} = R_{DS(on)(LOW)} * I_{LIM}/50\mu A \quad (5)$$

For example, a conservative 15A current limit in a 10A design with a minimum  $R_{DS(on)}$  of 10m $\Omega$  would require a 3.3k $\Omega$  resistor. Because current sensing is done across the low side FET, no minimum high side on-time is necessary. In the current limit mode the LM2727/37 will turn the high side off and keep low side on for as long as necessary. The chip also discharges the soft start capacitor through a fixed 95 $\mu A$  source. In this way, smooth ramping up of the output voltage as with a normal soft start is ensured. The output of the LM2727/37 internal error amplifier is limited by the voltage on the soft start capacitor. Hence, discharging the soft start capacitor reduces the maximum duty cycle D of the controller. During severe current limit, this reduction in duty cycle will reduce the output voltage, if the current limit conditions lasts for an extended time.

During the first few nanoseconds after the low side gate turns on, the low side FET body diode conducts. This causes an additional 0.7V drop in  $V_{DS}$ . The range of  $V_{DS}$  is normally much lower. For example, if  $R_{DS(on)}$  were 10m $\Omega$  and the current through the FET was 10A,  $V_{DS}$  would be 0.1V. The current limit would see 0.7V as a 70A current and enter current limit immediately. Hence current limit is masked during the time it takes for the high side switch to turn off and the low side switch to turn on.

## UVPI/OVP

The output undervoltage protection and overvoltage protection mechanisms engage at 70% and 118% of the target output voltage, respectively. In either case, the LM2727 will turn off the high side switch and turn on the low side switch, and discharge the soft start capacitor through a MOSFET switch. The chip remains in this state until the shutdown pin has been pulled to a logic low and then released. The UVP function is masked only during the first charging of the soft start capacitor, when voltage is first applied to the  $V_{CC}$  pin. In contrast, the LM2737 is designed to continue operating during UVP or OVP conditions, and to resume normal operation once the fault condition is cleared. As with the LM2727, the powergood flag goes low during this time, giving a logic-level warning signal.

## SHUT DOWN

If the shutdown pin  $\overline{SD}$  is pulled low, the LM2727/37 discharges the soft start capacitor through a MOSFET switch. The high side switch is turned off and the low side switch is turned on. The LM2727/37 remains in this state until  $\overline{SD}$  is released.

## DESIGN CONSIDERATIONS

The following is a design procedure for all the components needed to create the circuit shown in [Figure 26](#) in the Example Circuits section, a 5V in to 1.2V out converter, capable of delivering 10A with an efficiency of 85%. The switching frequency is 300kHz. The same procedures can be followed to create the circuit shown in [Figure 26](#), [Figure 27](#), and to create many other designs with varying input voltages, output voltages, and output currents.

### INPUT CAPACITOR

The input capacitors in a Buck switching converter are subjected to high stress due to the input current waveform, which is a square wave. Hence input caps are selected for their ripple current capability and their ability to withstand the heat generated as that ripple current runs through their ESR. Input rms ripple current is approximately:

$$I_{rms\_rip} = I_o * \sqrt{D(1 - D)} \quad (6)$$

The power dissipated by each input capacitor is:

$$P_D = \frac{I_{rms\_rip}^2 * ESR}{n^2} \quad (7)$$

Here,  $n$  is the number of capacitors, and indicates that power loss in each cap decreases rapidly as the number of input caps increase. The worst-case ripple for a Buck converter occurs during full load, when the duty cycle  $D = 50\%$ .

In the 5V to 1.2V case,  $D = 1.2/5 = 0.24$ . With a 10A maximum load the ripple current is 4.3A. The Sanyo 10MV5600AX aluminum electrolytic capacitor has a ripple current rating of 2.35A, up to 105°C. Two such capacitors make a conservative design that allows for unequal current sharing between individual caps. Each capacitor has a maximum ESR of 18mΩ at 100 kHz. Power loss in each device is then 0.05W, and total loss is 0.1W. Other possibilities for input and output capacitors include MLCC, tantalum, OSCON, SP, and POSCAPS.

### INPUT INDUCTOR

The input inductor serves two basic purposes. First, in high power applications, the input inductor helps insulate the input power supply from switching noise. This is especially important if other switching converters draw current from the same supply. Noise at high frequency, such as that developed by the LM2727 at 1MHz operation, could pass through the input stage of a slower converter, contaminating and possibly interfering with its operation.

An input inductor also helps shield the LM2727 from high frequency noise generated by other switching converters. The second purpose of the input inductor is to limit the input current slew rate. During a change from no-load to full-load, the input inductor sees the highest voltage change across it, equal to the full load current times the input capacitor ESR. This value divided by the maximum allowable input current slew rate gives the minimum input inductance:

$$L_{in} = \frac{\Delta V}{\left(\frac{di}{dt}\right)_{max}} \quad (8)$$

In the case of a desktop computer system, the input current slew rate is the system power supply or "silver box" output current slew rate, which is typically about 0.1A/μs. Total input capacitor ESR is 9mΩ, hence ΔV is 10\*0.009 = 90 mV, and the minimum inductance required is 0.9μH. The input inductor should be rated to handle the DC input current, which is approximated by:

$$I_{IN-DC} = \frac{I_o * D}{\eta} \quad (9)$$

In this case  $I_{IN-DC}$  is about 2.8A. One possible choice is the TDK SLF12575T-1R2N8R2, a 1.2μH device that can handle 8.2Arms, and has a DCR of 7mΩ.

## OUTPUT INDUCTOR

The output inductor forms the first half of the power stage in a Buck converter. It is responsible for smoothing the square wave created by the switching action and for controlling the output current ripple. ( $\Delta I_o$ ) The inductance is chosen by selecting between tradeoffs in efficiency and response time. The smaller the output inductor, the more quickly the converter can respond to transients in the load current. As shown in the efficiency calculations, however, a smaller inductor requires a higher switching frequency to maintain the same level of output current ripple. An increase in frequency can mean increasing loss in the FETs due to the charging and discharging of the gates. Generally the switching frequency is chosen so that conduction loss outweighs switching loss. The equation for output inductor selection is:

$$L = \frac{V_{in} - V_o}{\Delta I_o * F_{SW}} * D \quad (10)$$

Plugging in the values for output current ripple, input voltage, output voltage, switching frequency, and assuming a 40% peak-to-peak output current ripple yields an inductance of 1.5μH. The output inductor must be rated to handle the peak current (also equal to the peak switch current), which is  $(I_o + 0.5*\Delta I_o)$ . This is 12A for a 10A design. The Coilcraft D05022-152HC is 1.5μH, is rated to 15Arms, and has a DCR of 4mΩ.

## OUTPUT CAPACITOR

The output capacitor forms the second half of the power stage of a Buck switching converter. It is used to control the output voltage ripple ( $\Delta V_o$ ) and to supply load current during fast load transients.

In this example the output current is 10A and the expected type of capacitor is an aluminum electrolytic, as with the input capacitors. (Other possibilities include ceramic, tantalum, and solid electrolyte capacitors, however the ceramic type often do not have the large capacitance needed to supply current for load transients, and tantalums tend to be more expensive than aluminum electrolytic.) Aluminum capacitors tend to have very high capacitance and fairly low ESR, meaning that the ESR zero, which affects system stability, will be much lower than the switching frequency. The large capacitance means that at switching frequency, the ESR is dominant, hence the type and number of output capacitors is selected on the basis of ESR. One simple formula to find the maximum ESR based on the desired output voltage ripple,  $\Delta V_o$ , and the designed output current ripple,  $\Delta I_o$ , is:

$$ESR_{MAX} = \frac{\Delta V_o}{\Delta I_o} \quad (11)$$

In this example, in order to maintain a 2% peak-to-peak output voltage ripple and a 40% peak-to-peak inductor current ripple, the required maximum ESR is 6mΩ. Three Sanyo 10MV5600AX capacitors in parallel will give an equivalent ESR of 6mΩ. The total bulk capacitance of 16.8mF is enough to supply even severe load transients. Using the same capacitors for both input and output also keeps the bill of materials simple.

## MOSFETS

MOSFETS are a critical part of any switching controller and have a direct impact on the system efficiency. In this case the target efficiency is 85% and this is the variable that will determine which devices are acceptable. Loss from the capacitors, inductors, and the LM2727 itself are detailed in the Efficiency section, and come to about 0.54W. To meet the target efficiency, this leaves 1.45W for the FET conduction loss, gate charging loss, and switching loss. Switching loss is particularly difficult to estimate because it depends on many factors. When the load current is more than about 1 or 2 amps, conduction losses outweigh the switching and gate charging losses. This allows FET selection based on the  $R_{DS(on)}$  of the FET. Adding the FET switching and gate-charging losses to the equation leaves 1.2W for conduction losses. The equation for conduction loss is:

$$P_{CND} = D(I_o^2 * R_{DS(on)} * k) + (1-D)(I_o^2 * R_{DS(on)} * k) \quad (12)$$

The factor k is a constant which is added to account for the increasing  $R_{DS(on)}$  of a FET due to heating. Here,  $k = 1.3$ . The Si4442DY has a typical  $R_{DS(on)}$  of 4.1mΩ. When plugged into the equation for  $P_{CND}$  the result is a loss of 0.533W. If this design were for a 5V to 2.5V circuit, an equal number of FETs on the high and low sides would be the best solution. With the duty cycle  $D = 0.24$ , it becomes apparent that the low side FET carries the load current 76% of the time. Adding a second FET in parallel to the bottom FET could improve the efficiency by lowering the effective  $R_{DS(on)}$ . The lower the duty cycle, the more effective a second or even third FET can be. For a minimal increase in gate charging loss (0.054W) the decrease in conduction loss is 0.15W. What was an 85% design improves to 86% for the added cost of one SO-8 MOSFET.

## CONTROL LOOP COMPONENTS

The circuit is this design example and the others shown in the Example Circuits section have been compensated to improve their DC gain and bandwidth. The result of this compensation is better line and load transient responses. For the LM2727, the top feedback divider resistor,  $R_{fb2}$ , is also a part of the compensation. For the 10A, 5V to 1.2V design, the values are:

$C_{c1} = 4.7pF$  10%,  $C_{c2} = 1nF$  10%,  $R_c = 229k\Omega$  1%. These values give a phase margin of 63° and a bandwidth of 29.3kHz.

## SUPPORT CAPACITORS AND RESISTORS

The  $C_{inx}$  capacitors are high frequency bypass devices, designed to filter harmonics of the switching frequency and input noise. Two 1μF ceramic capacitors with a sufficient voltage rating (10V for the Circuit of [Figure 26](#)) will work well in almost any case.

$R_{bypass}$  and  $C_{bypass}$  are standard filter components designed to ensure smooth DC voltage for the chip supply and for the bootstrap structure, if it is used. Use 10Ω for the resistor and a 2.2μF ceramic for the cap.  $C_b$  is the bootstrap capacitor, and should be 0.1μF. (In the case of a separate, higher supply to the BOOTV pin, this 0.1μF cap can be used to bypass the supply.) Using a Schottky device for the bootstrap diode allows the minimum drop for both high and low side drivers. The On Semiconductor BAT54 or MBR0520 work well.

$R_p$  is a standard pull-up resistor for the open-drain power good signal, and should be 10kΩ. If this feature is not necessary, it can be omitted.

$R_{CS}$  is the resistor used to set the current limit. Since the design calls for a peak current magnitude ( $I_o + 0.5 * \Delta I_o$ ) of 12A, a safe setting would be 15A. (This is well below the saturation current of the output inductor, which is 25A.) Following the equation from the Current Limit section, use a 3.3kΩ resistor.

$R_{FADJ}$  is used to set the switching frequency of the chip. Following the equation in the Theory of Operation section, the closest 1% tolerance resistor to obtain  $f_{sw} = 300kHz$  is 88.7kΩ.

$C_{SS}$  depends on the users requirements. Based on the equation for  $C_{SS}$  in the Theory of Operation section, for a 3ms delay, a 12nF capacitor will suffice.

## EFFICIENCY CALCULATIONS

A reasonable estimation of the efficiency of a switching controller can be obtained by adding together the loss in each current carrying element and using the equation:

$$\eta = \frac{P_o}{P_o + P_{\text{total-loss}}} \quad (13)$$

The following shows an efficiency calculation to complement the Circuit of [Figure 26](#). Output power for this circuit is  $1.2V \times 10A = 12W$ .

### Chip Operating Loss

$$P_{IQ} = I_{Q-VCC} * V_{CC} \quad (14)$$

$$2mA \times 5V = 0.01W$$

### FET Gate Charging Loss

$$P_{GC} = n * V_{CC} * Q_{GS} * f_{OSC} \quad (15)$$

The value n is the total number of FETs used. The Si4442DY has a typical total gate charge,  $Q_{GS}$ , of 36nC and an  $r_{ds-on}$  of 4.1mΩ. For a single FET on top and bottom:  $2 * 5 * 36E^{-9} * 300,000 = 0.108W$

### FET Switching Loss

$$P_{SW} = 0.5 * V_{in} * I_o * (t_r + t_f) * f_{OSC} \quad (16)$$

The Si4442DY has a typical rise time  $t_r$  and fall time  $t_f$  of 11 and 47ns, respectively.  $0.5 * 5 * 10 * 58E^{-9} * 300,000 = 0.435W$

### FET Conduction Loss

$$P_{Cn} = 0.533W \quad (17)$$

### Input Capacitor Loss

$$P_{Cin} = \frac{I_{rms-rip}^2 * ESR}{n} \quad (18)$$

$$I_{rms-rip} = I_o * \sqrt{D(1-D)} \quad (19)$$

$$4.28^2 * 0.018 / 2 = 0.084W$$

### Input Inductor Loss

$$P_{Lin} = I_{in}^2 * DCR_{input-L} \quad (20)$$

$$I_{IN} = \frac{I_o * D}{\eta_{est'd}} \quad (21)$$

$$2.82^2 * 0.007 = 0.055W$$

### Output Inductor Loss

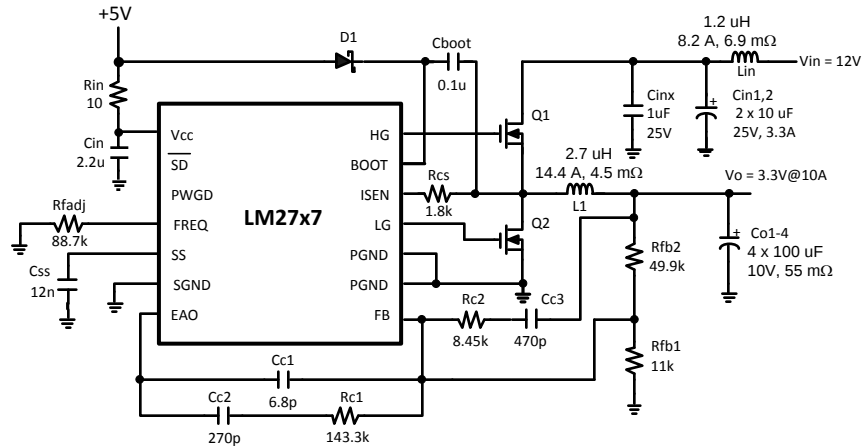
$$P_{Lout} = I_o^2 * DCR_{output-L} \quad (22)$$

$$10^2 * 0.004 = 0.4W$$

### System Efficiency

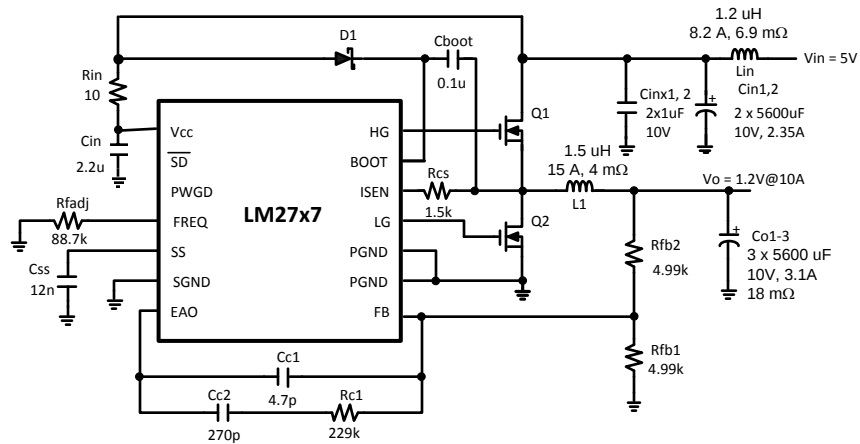
$$\frac{12}{12 + 1.625} = 88\% \quad (23)$$

## Example Circuits



**Figure 25. 5V-16V to 3.3V, 10A, 300kHz**

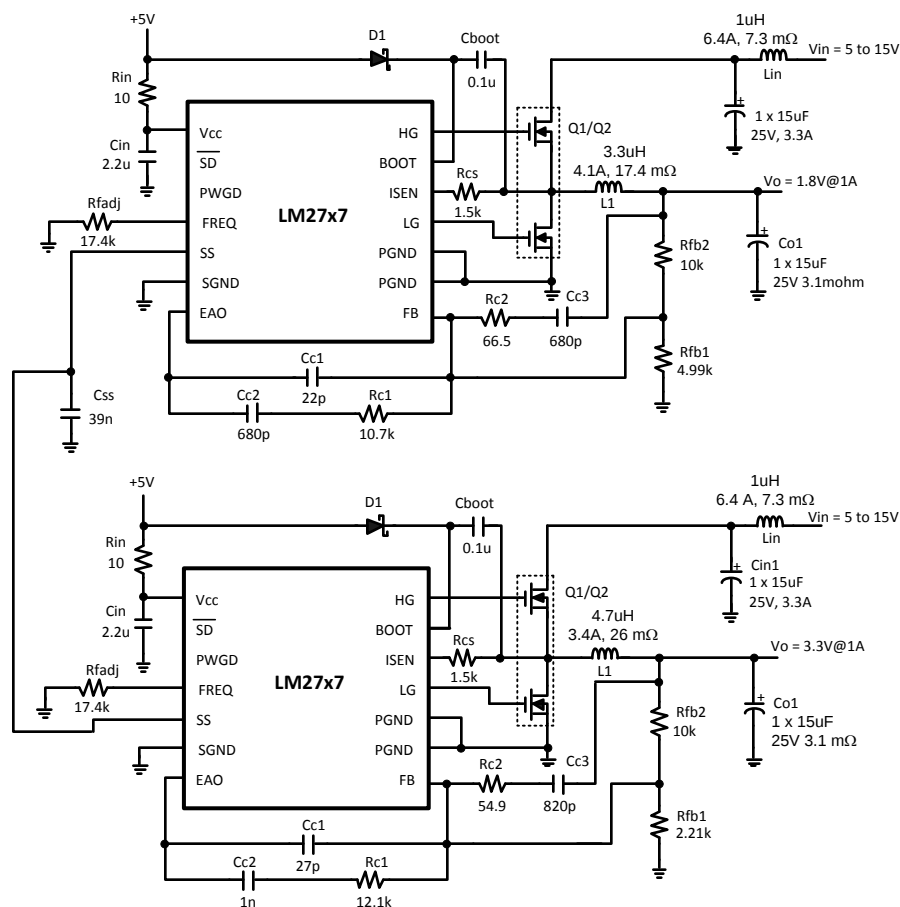
This circuit and the one featured on the front page have been designed to deliver high current and high efficiency in a small package, both in area and in height. The tallest component in this circuit is the inductor L1, which is 6mm tall. The compensation has been designed to tolerate input voltages from 5 to 16V.



**Figure 26. 5V to 1.2V, 10A, 300kHz**

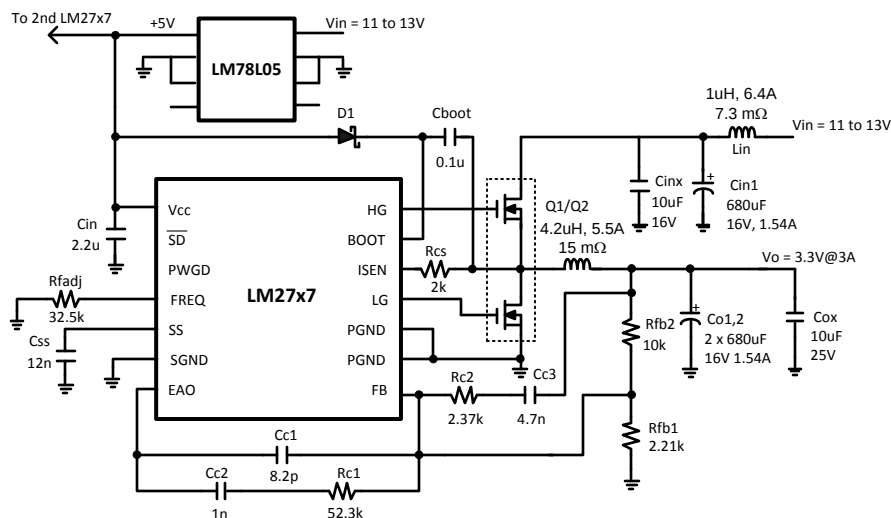
This circuit design, detailed in the Design Considerations section, uses inexpensive aluminum capacitors and off-the-shelf inductors. It can deliver 10A at better than 85% efficiency. Large bulk capacitance on input and output ensure stable operation.





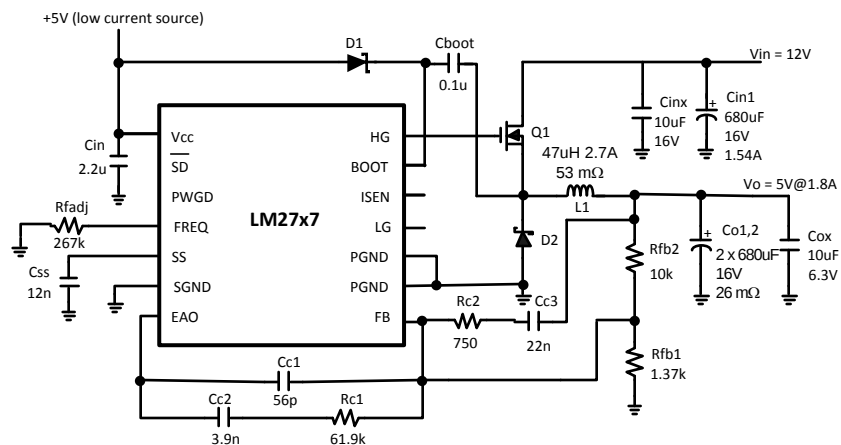
**Figure 29. 1.8V and 3.3V, 1A, 1.4MHz, Simultaneous**

The circuits in [Figure 29](#) are intended for ADSL applications, where the high switching frequency keeps noise out of the data transmission range. In this design, the 1.8 and 3.3V outputs come up simultaneously by using the same softstart capacitor. Because two current sources now charge the same capacitor, the capacitance must be doubled to achieve the same softstart time. (Here, 40nF is used to achieve a 5ms softstart time.) A common softstart capacitor means that, should one circuit enter current limit, the other circuit will also enter current limit. In addition, if both circuits are built with the LM2727, a UVP or OVP fault on one circuit will cause both circuits to latch off. The additional compensation components Rc2 and Cc3 are needed for the low ESR, all ceramic output capacitors, and the wide (3x) range of Vin.



**Figure 30. 12V Unregulated to 3.3V, 3A, 750kHz**

This circuit shows the LM27x7 paired with a cost effective solution to provide the 5V chip power supply, using no extra components other than the LM78L05 regulator itself. The input voltage comes from a 'brick' power supply which does not regulate the 12V line tightly. Additional, inexpensive 10uF ceramic capacitors (Cinx and Cox) help isolate devices with sensitive databands, such as DSL and cable modems, from switching noise and harmonics.



**Figure 31. 12V to 5V, 1.8A, 100kHz**

In situations where low cost is very important, the LM27x7 can also be used as an asynchronous controller, as shown in the above circuit. Although a schottky diode in place of the bottom FET will not be as efficient, it will cost much less than the FET. The 5V at low current needed to run the LM27x7 could come from a zener diode or inexpensive regulator, such as the one shown in [Figure 30](#). Because the LM27x7 senses current in the low side MOSFET, the current limit feature will not function in an asynchronous design. The ISEN pin should be left open in this case.

**Table 1. Bill of Materials for Typical Application Circuit**

| ID         | Part Number      | Type                   | Size          | Parameters        | Qty. | Vendor            |
|------------|------------------|------------------------|---------------|-------------------|------|-------------------|
| U1         | LM2727           | Synchronous Controller | TSSOP-14      | TSSOP-14          | 1    | Texas Instruments |
| Q1, Q2     | Si4884DY         | N-MOSFET               | SO-8          | 30V, 4.1mΩ, 36nC  | 1    | Vishay            |
| L1         | RLF7030T-1R5N6R1 | Inductor               | 7.1x7.1x3.2mm | 1.5μH, 6.1A 9.6mΩ | 1    | TDK               |
| Cin1, Cin2 | C2012X5R1J106M   | MLCC                   | 0805          | 10μF 6.3V         | 2    | TDK               |
| Cinx       | C3216X7R1E105K   | Capacitor              | 1206          | 1μF, 25V          | 1    | TDK               |
| Co1, Co2   | 6MV2200WG        | AL-E                   | 10mm D 20mm H | 2200μF 6.3V125mΩ  | 2    | Sanyo             |
| Cboot      | VJ1206X104XXA    | Capacitor              | 1206          | 0.1μF, 25V        | 1    | Vishay            |
| Cin        | C3216X7R1E225K   | Capacitor              | 1206          | 0.1μF, 25V        | 1    | TDK               |
| Css        | VJ1206X123KXX    | Capacitor              | 1206          | 12nF, 25V         | 1    | Vishay            |
| Cc1        | VJ1206A2R2KXX    | Capacitor              | 1206          | 2.2pF 10%         | 1    | Vishay            |
| Cc2        | VJ1206A181KXX    | Capacitor              | 1206          | 180pF 10%         | 1    | Vishay            |
| Rin        | CRCW1206100J     | Resistor               | 1206          | 10Ω 5%            | 1    | Vishay            |
| Rfadj      | CRCW12066342F    | Resistor               | 1206          | 63.4kΩ 1%         | 1    | Vishay            |
| Rc1        | CRCW12063923F    | Resistor               | 1206          | 392kΩ 1%          | 1    | Vishay            |
| Rfb1       | CRCW12061002F    | Resistor               | 1206          | 10kΩ 1%           | 1    | Vishay            |
| Rfb2       | CRCW12061002F    | Resistor               | 1206          | 10kΩ 1%           | 1    | Vishay            |
| Rcs        | CRCW1206222J     | Resistor               | 1206          | 2.2kΩ 5%          | 1    | Vishay            |

**Table 2. Bill of Materials for Circuit of Figure 25  
(Identical to BOM for 1.5V except as noted below)**

| ID                 | Part Number       | Type      | Size          | Parameters         | Qty. | Vendor |
|--------------------|-------------------|-----------|---------------|--------------------|------|--------|
| L1                 | RLF12560T-2R7N110 | Inductor  | 12.5x12.8x6mm | 2.7μH, 14.4A 4.5mΩ | 1    | TDK    |
| Co1, Co2, Co3, Co4 | 10TPB100M         | POSCAP    | 7.3x4.3x2.8mm | 100μF 10V 1.9Arms  | 4    | Sanyo  |
| Cc1                | VJ1206A6R8KXX     | Capacitor | 1206          | 6.8pF 10%          | 1    | Vishay |
| Cc2                | VJ1206A271KXX     | Capacitor | 1206          | 270pF 10%          | 1    | Vishay |
| Cc3                | VJ1206A471KXX     | Capacitor | 1206          | 470pF 10%          | 1    | Vishay |
| Rc2                | CRCW12068451F     | Resistor  | 1206          | 8.45kΩ 1%          | 1    | Vishay |
| Rfb1               | CRCW12061102F     | Resistor  | 1206          | 11kΩ 1%            | 1    | Vishay |

**Table 3. Bill of Materials for Circuit of Figure 26**

| ID            | Part Number       | Type                   | Size            | Parameters               | Qty. | Vendor            |
|---------------|-------------------|------------------------|-----------------|--------------------------|------|-------------------|
| U1            | LM2727            | Synchronous Controller | TSSOP-14        |                          | 1    | Texas Instruments |
| Q1            | Si4442DY          | N-MOSFET               | SO-8            | 30V, 4.1mΩ, @ 4.5V, 36nC | 1    | Vishay            |
| Q2            | Si4442DY          | N-MOSFET               | SO-8            | 30V, 4.1mΩ, @ 4.5V, 36nC | 1    | Vishay            |
| D1            | BAT-54            | Schottky Diode         | SOT-23          | 30V                      | 1    | Vishay            |
| Lin           | SLF12575T-1R2N8R2 | Inductor               | 12.5x12.5x7.5mm | 12μH, 8.2A, 6.9mΩ        | 1    | Coilcraft         |
| L1            | D05022-152HC      | Inductor               | 22.35x16.26x8mm | 1.5μH, 15A, 4mΩ          | 1    | Coilcraft         |
| Cin1, Cin2    | 10MV5600AX        | Aluminum Electrolytic  | 16mm D 25mm H   | 5600μF10V 2.35Arms       | 2    | Sanyo             |
| Cinx          | C3216X7R1E105K    | Capacitor              | 1206            | 1μF, 25V                 | 1    | TDK               |
| Co1, Co2, Co3 | 10MV5600AX        | Aluminum Electrolytic  | 16mm D 25mm H   | 5600μF10V 2.35Arms       | 2    | Sanyo             |
| Cboot         | VJ1206X104XXA     | Capacitor              | 1206            | 0.1μF, 25V               | 1    | Vishay            |
| Cin           | C3216X7R1E225K    | Capacitor              | 1206            | 2.2μF, 25V               | 1    | TDK               |
| Css           | VJ1206X123KXX     | Capacitor              | 1206            | 12nF, 25V                | 1    | Vishay            |
| Cc1           | VJ1206A4R7KXX     | Capacitor              | 1206            | 4.7pF 10%                | 1    | Vishay            |

**Table 3. Bill of Materials for Circuit of Figure 26 (continued)**

| ID    | Part Number   | Type      | Size | Parameters | Qty. | Vendor |
|-------|---------------|-----------|------|------------|------|--------|
| Cc2   | VJ1206A102KXX | Capacitor | 1206 | 1nF 10%    | 1    | Vishay |
| Rin   | CRCW1206100J  | Resistor  | 1206 | 10Ω 5%     | 1    | Vishay |
| Rfadj | CRCW12068872F | Resistor  | 1206 | 88.7kΩ 1%  | 1    | Vishay |
| Rc1   | CRCW12062293F | Resistor  | 1206 | 229kΩ 1%   | 1    | Vishay |
| Rfb1  | CRCW12064991F | Resistor  | 1206 | 4.99kΩ 1%  | 1    | Vishay |
| Rfb2  | CRCW12064991F | Resistor  | 1206 | 4.99kΩ 1%  | 1    | Vishay |
| Rcs   | CRCW1206152J  | Resistor  | 1206 | 1.5kΩ 5%   | 1    | Vishay |

**Table 4. Bill of Materials for Circuit of Figure 27**

| ID    | Part Number    | Type                    | Size              | Parameters                         | Qty. | Vendor            |
|-------|----------------|-------------------------|-------------------|------------------------------------|------|-------------------|
| U1    | LM2727         | Synchronous Controller  | TSSOP-14          |                                    | 1    | Texas Instruments |
| Q1/Q2 | Si4826DY       | Asymetric Dual N-MOSFET | SO-8              | 30V, 24mΩ/ 8nC<br>Top 16.5mΩ/ 15nC | 1    | Vishay            |
| L1    | DO3316P-222    | Inductor                | 12.95x9.4x 5.21mm | 2.2μH, 6.1A, 12mΩ                  | 1    | Coilcraft         |
| Cin1  | 10TPB100ML     | POSCAP                  | 7.3x4.3x3.1mm     | 100μF 10V 1.9Arms                  | 1    | Sanyo             |
| Co1   | 4TPB220ML      | POSCAP                  | 7.3x4.3x3.1mm     | 220μF 4V 1.9Arms                   | 1    | Sanyo             |
| Cc    | C3216X7R1E105K | Capacitor               | 1206              | 1μF, 25V                           | 1    | TDK               |
| Cin   | C3216X7R1E225K | Capacitor               | 1206              | 2.2μF, 25V                         | 1    | TDK               |
| Css   | VJ1206X123KXX  | Capacitor               | 1206              | 12nF, 25V                          | 1    | Vishay            |
| Cc1   | VJ1206A100KXX  | Capacitor               | 1206              | 10pF 10%                           | 1    | Vishay            |
| Cc2   | VJ1206A561KXX  | Capacitor               | 1206              | 560pF 10%                          | 1    | Vishay            |
| Rin   | CRCW1206100J   | Resistor                | 1206              | 10Ω 5%                             | 1    | Vishay            |
| Rfadj | CRCW12064222F  | Resistor                | 1206              | 42.2kΩ 1%                          | 1    | Vishay            |
| Rc1   | CRCW12065112F  | Resistor                | 1206              | 51.1kΩ 1%                          | 1    | Vishay            |
| Rfb1  | CRCW12062491F  | Resistor                | 1206              | 2.49kΩ 1%                          | 1    | Vishay            |
| Rfb2  | CRCW12064991F  | Resistor                | 1206              | 4.99kΩ 1%                          | 1    | Vishay            |
| Rcs   | CRCW1206272J   | Resistor                | 1206              | 2.7kΩ 5%                           | 1    | Vishay            |

**Table 5. Bill of Materials for Circuit of Figure 28**

| ID            | Part Number    | Type                   | Size             | Parameters                    | Qty. | Vendor            |
|---------------|----------------|------------------------|------------------|-------------------------------|------|-------------------|
| U1            | LM2727         | Synchronous Controller | TSSOP-14         |                               | 1    | Texas Instruments |
| Q1            | Si4884DY       | N-MOSFET               | SO-8             | 30V, 13.5mΩ, @ 4.5V<br>15.3nC | 1    | Vishay            |
| Q2            | Si4884DY       | N-MOSFET               | SO-8             | 30V, 13.5mΩ, @ 4.5V<br>15.3nC | 1    | Vishay            |
| D1            | BAT-54         | Schottky Diode         | SOT-23           | 30V                           | 1    | Vishay            |
| Lin           | P1166.102T     | Inductor               | 7.29x7.29 3.51mm | 1μH, 11A 3.7mΩ                | 1    | Pulse             |
| L1            | P1168.102T     | Inductor               | 12x12x4.5 mm     | 1μH, 11A, 3.7mΩ               | 1    | Pulse             |
| Cin1          | 10MV5600AX     | Aluminum Electrolytic  | 16mm D 25mm H    | 5600μF 10V 2.35Arms           | 1    | Sanyo             |
| Cinx          | C3216X7R1E105K | Capacitor              | 1206             | 1μF, 25V                      | 1    | TDK               |
| Co1, Co2, Co3 | 16MV4700WX     | Aluminum Electrolytic  | 12.5mm D 30mm H  | 4700μF 16V 2.8Arms            | 2    | Sanyo             |
| Cboot         | VJ1206X104XXA  | Capacitor              | 1206             | 0.1μF, 25V                    | 1    | Vishay            |
| Cin           | C3216X7R1E225K | Capacitor              | 1206             | 2.2μF, 25V                    | 1    | TDK               |
| Css           | VJ1206X123KXX  | Capacitor              | 1206             | 12nF, 25V                     | 1    | Vishay            |
| Cc1           | VJ1206A4R7KXX  | Capacitor              | 1206             | 4.7pF 10%                     | 1    | Vishay            |

**Table 5. Bill of Materials for Circuit of Figure 28 (continued)**

| ID    | Part Number   | Type      | Size | Parameters | Qty. | Vendor |
|-------|---------------|-----------|------|------------|------|--------|
| Cc2   | VJ1206A681KXX | Capacitor | 1206 | 680pF 10%  | 1    | Vishay |
| Rin   | CRCW1206100J  | Resistor  | 1206 | 10Ω 5%     | 1    | Vishay |
| Rfadj | CRCW12064992F | Resistor  | 1206 | 49.9kΩ 1%  | 1    | Vishay |
| Rc1   | CRCW12061473F | Resistor  | 1206 | 147kΩ 1%   | 1    | Vishay |
| Rfb1  | CRCW12061492F | Resistor  | 1206 | 14.9kΩ 1%  | 1    | Vishay |
| Rfb2  | CRCW12064991F | Resistor  | 1206 | 4.99kΩ 1%  | 1    | Vishay |
| Rcs   | CRCW1206332J  | Resistor  | 1206 | 3.3kΩ 5%   | 1    | Vishay |

**Table 6. Bill of Materials for Circuit of Figure 29**

| ID    | Part Number      | Type                     | Size          | Parameters                         | Qty. | Vendor            |
|-------|------------------|--------------------------|---------------|------------------------------------|------|-------------------|
| U1    | LM2727           | Synchronous Controller   | TSSOP-14      |                                    | 1    | Texas Instruments |
| Q1/Q2 | Si4826DY         | Assymetric Dual N-MOSFET | SO-8          | 30V, 24mΩ/ 8nC<br>Top 16.5mΩ/ 15nC | 1    | Vishay            |
| D1    | BAT-54           | Schottky Diode           | SOT-23        | 30V                                | 1    | Vishay            |
| Lin   | RLF7030T-1R0N64  | Inductor                 | 6.8x7.1x3.2mm | 1μH, 6.4A, 7.3mΩ                   | 1    | TDK               |
| L1    | RLF7030T-3R3M4R1 | Inductor                 | 6.8x7.1x3.2mm | 3.3μH, 4.1A, 17.4mΩ                | 1    | TDK               |
| Cin1  | C4532X5R1E156M   | MLCC                     | 1812          | 15μF 25V 3.3Arms                   | 1    | Sanyo             |
| Co1   | C4532X5R1E156M   | MLCC                     | 1812          | 15μF 25V 3.3Arms                   | 1    | Sanyo             |
| Cboot | VJ1206X104XXA    | Capacitor                | 1206          | 0.1μF, 25V                         | 1    | TDK               |
| Cin   | C3216X7R1E225K   | Capacitor                | 1206          | 2.2μF, 25V                         | 1    | TDK               |
| Css   | VJ1206X393KXX    | Capacitor                | 1206          | 39nF, 25V                          | 1    | Vishay            |
| Cc1   | VJ1206A220KXX    | Capacitor                | 1206          | 22pF 10%                           | 1    | Vishay            |
| Cc2   | VJ1206A681KXX    | Capacitor                | 1206          | 680pF 10%                          | 1    | Vishay            |
| Cc3   | VJ1206A681KXX    | Capacitor                | 1206          | 680pF 10%                          | 1    | Vishay            |
| Rin   | CRCW1206100J     | Resistor                 | 1206          | 10Ω 5%                             | 1    | Vishay            |
| Rfadj | CRCW12061742F    | Resistor                 | 1206          | 17.4kΩ 1%                          | 1    | Vishay            |
| Rc1   | CRCW12061072F    | Resistor                 | 1206          | 10.7kΩ 1%                          | 1    | Vishay            |
| Rc2   | CRCW120666R5F    | Resistor                 | 1206          | 66.5Ω 1%                           | 1    | Vishay            |
| Rfb1  | CRCW12064991F    | Resistor                 | 1206          | 4.99kΩ 1%                          | 1    | Vishay            |
| Rfb2  | CRCW12061002F    | Resistor                 | 1206          | 10kΩ 1%                            | 1    | Vishay            |
| Rcs   | CRCW1206152J     | Resistor                 | 1206          | 1.5kΩ 5%                           | 1    | Vishay            |

**Table 7. Bill of Materials for 3.3V Circuit of Figure 29  
(Identical to BOM for 1.8V except as noted below)**

| ID   | Part Number      | Type      | Size           | Parameters        | Qty. | Vendor |
|------|------------------|-----------|----------------|-------------------|------|--------|
| L1   | RLF7030T-4R7M3R4 | Inductor  | 6.8x7.1x 3.2mm | 4.7μH, 3.4A, 26mΩ | 1    | TDK    |
| Cc1  | VJ1206A270KXX    | Capacitor | 1206           | 27pF 10%          | 1    | Vishay |
| Cc2  | VJ1206X102KXX    | Capacitor | 1206           | 1nF 10%           | 1    | Vishay |
| Cc3  | VJ1206A821KXX    | Capacitor | 1206           | 820pF 10%         | 1    | Vishay |
| Rc1  | CRCW12061212F    | Resistor  | 1206           | 12.1kΩ 1%         | 1    | Vishay |
| Rc2  | CRCW12054R9F     | Resistor  | 1206           | 54.9Ω 1%          | 1    | Vishay |
| Rfb1 | CRCW12062211F    | Resistor  | 1206           | 2.21kΩ 1%         | 1    | Vishay |
| Rfb2 | CRCW12061002F    | Resistor  | 1206           | 10kΩ 1%           | 1    | Vishay |

**Table 8. Bill of Materials for Circuit of Figure 30**

| ID      | Part Number       | Type                     | Size              | Parameters                         | Qty. | Vendor            |
|---------|-------------------|--------------------------|-------------------|------------------------------------|------|-------------------|
| U1      | LM2727            | Synchronous Controller   | TSSOP-14          |                                    | 1    | Texas Instruments |
| U2      | LM78L05           | Voltage Regulator        | SO-8              |                                    | 1    | Texas Instruments |
| Q1/Q2   | Si4826DY          | Assymetric Dual N-MOSFET | SO-8              | 30V, 24mΩ/ 8nC<br>Top 16.5mΩ/ 15nC | 1    | Vishay            |
| D1      | BAT-54            | Schottky Diode           | SOT-23            | 30V                                | 1    | Vishay            |
| Lin     | RLF7030T-1R0N64   | Inductor                 | 6.8x7.1x3.2mm     | 1μH, 6.4A, 7.3mΩ                   | 1    | TDK               |
| L1      | SLF12565T-4R2N5R5 | Inductor                 | 12.5x12.5x6.5mm   | 4.2μH, 5.5A, 15mΩ                  | 1    | TDK               |
| Cin1    | 16MV680WG         | Al-E                     | D: 10mm L: 12.5mm | 680μF 16V 3.4Arms                  | 1    | Sanyo             |
| Cinx    | C3216X5R1C106M    | MLCC                     | 1210              | 10μF 16V 3.4Arms                   | 1    | TDK               |
| Co1 Co2 | 16MV680WG         | MLCC                     | 1812              | 15μF 25V 3.3Arms                   | 1    | Sanyo             |
| Cox     | C3216X5R10J06M    | MLCC                     | 1206              | 10μF 6.3V 2.7A                     |      | TDK               |
| Cboot   | VJ1206X104XXA     | Capacitor                | 1206              | 0.1μF, 25V                         | 1    | Vishay            |
| Cin     | C3216X7R1E225K    | Capacitor                | 1206              | 2.2μF, 25V                         | 1    | TDK               |
| Css     | VJ1206X123KXX     | Capacitor                | 1206              | 12nF, 25V                          | 1    | Vishay            |
| Cc1     | VJ1206A8R2KXX     | Capacitor                | 1206              | 8.2pF 10%                          | 1    | Vishay            |
| Cc2     | VJ1206X102KXX     | Capacitor                | 1206              | 1nF 10%                            | 1    | Vishay            |
| Cc3     | VJ1206X472KXX     | Capacitor                | 1206              | 4.7nF 10%                          | 1    | Vishay            |
| Rfadj   | CRCW12063252F     | Resistor                 | 1206              | 32.5kΩ 1%                          | 1    | Vishay            |
| Rc1     | CRCW12065232F     | Resistor                 | 1206              | 52.3kΩ 1%                          | 1    | Vishay            |
| Rc2     | CRCW120662371F    | Resistor                 | 1206              | 2.37Ω 1%                           | 1    | Vishay            |
| Rfb1    | CRCW12062211F     | Resistor                 | 1206              | 2.21kΩ 1%                          | 1    | Vishay            |
| Rfb2    | CRCW12061002F     | Resistor                 | 1206              | 10kΩ 1%                            | 1    | Vishay            |
| Rcs     | CRCW1206202J      | Resistor                 | 1206              | 2kΩ 5%                             | 1    | Vishay            |

**Table 9. Bill of Materials for Circuit of Figure 31**

| ID       | Part Number       | Type                   | Size              | Parameters           | Qty. | Vendor            |
|----------|-------------------|------------------------|-------------------|----------------------|------|-------------------|
| U1       | LM2727            | Synchronous Controller | TSSOP-14          |                      | 1    | Texas Instruments |
| Q1       | Si4894DY          | N-MOSFET               | SO-8              | 30V, 15mΩ, 11.5nC    | 1    | Vishay            |
| D2       | MBRS330T3         | Schottky Diode         | SO-8              | 30V, 3A              | 1    | ON                |
| L1       | SLF12565T-470M2R4 | Inductor               | 12.5x12.8x 4.7mm  | 47μH, 2.7A 53mΩ      | 1    | TDK               |
| D1       | MBR0520           | Schottky Diode         | 1812              | 20V 0.5A             | 1    | ON                |
| Cin1     | 16MV680WG         | Al-E                   | 1206              | 680μF, 16V, 1.54Arms | 1    | Sanyo             |
| Cinx     | C3216X5R1C106M    | MLCC                   | 1206              | 10μF, 16V, 3.4Arms   | 1    | TDK               |
| Co1, Co2 | 16MV680WG         | Al-E                   | D: 10mm L: 12.5mm | 680μF 16V 26mΩ       | 2    | Sanyo             |
| Cox      | C3216X5R10J06M    | MLCC                   | 1206              | 10μF, 6.3V 2.7A      | 1    | TDK               |
| Cboot    | VJ1206X104XXA     | Capacitor              | 1206              | 0.1μF, 25V           | 1    | Vishay            |
| Cin      | C3216X7R1E225K    | Capacitor              | 1206              | 2.2μF, 25V           | 1    | TDK               |
| Css      | VJ1206X123KXX     | Capacitor              | 1206              | 12nF, 25V            | 1    | Vishay            |
| Cc1      | VJ1206A561KXX     | Capacitor              | 1206              | 56pF 10%             | 1    | Vishay            |
| Cc2      | VJ1206X392KXX     | Capacitor              | 1206              | 3.9nF 10%            | 1    | Vishay            |
| Cc3      | VJ1206X223KXX     | Capacitor              | 1206              | 22nF 10%             | 1    | Vishay            |
| Rfadj    | CRCW12062673F     | Resistor               | 1206              | 267kΩ 1%             | 1    | Vishay            |
| Rc1      | CRCW12066192F     | Resistor               | 1206              | 61.9kΩ 1%            | 1    | Vishay            |
| Rc2      | CRCW12067503F     | Resistor               | 1206              | 750kΩ 1%             | 1    | Vishay            |

**Table 9. Bill of Materials for Circuit of [Figure 31](#) (continued)**

| ID   | Part Number   | Type     | Size | Parameters | Qty. | Vendor |
|------|---------------|----------|------|------------|------|--------|
| Rfb1 | CRCW12061371F | Resistor | 1206 | 1.37kΩ 1%  | 1    | Vishay |
| Rfb2 | CRCW12061002F | Resistor | 1206 | 10kΩ 1%    | 1    | Vishay |
| Rcs  | CRCW1206122F  | Resistor | 1206 | 1.2kΩ 5%   | 1    | Vishay |

## REVISION HISTORY

### Changes from Revision C (March 2013) to Revision D

### Page

- Changed layout of National Data Sheet to TI format ..... [23](#)

## PACKAGING INFORMATION

| Orderable part number           | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|---------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">LM2727MTC/NOPB</a>  | Active        | Production           | TSSOP (PW)   14 | 94   TUBE             | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | 0 to 125     | 2727<br>MTC         |
| LM2727MTC/NOPB.B                | Active        | Production           | TSSOP (PW)   14 | 94   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | 0 to 125     | 2727<br>MTC         |
| <a href="#">LM2727MTCX/NOPB</a> | Active        | Production           | TSSOP (PW)   14 | 2500   LARGE T&R      | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | 0 to 125     | 2727<br>MTC         |
| LM2727MTCX/NOPB.B               | Active        | Production           | TSSOP (PW)   14 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | 0 to 125     | 2727<br>MTC         |
| <a href="#">LM2737MTC/NOPB</a>  | Active        | Production           | TSSOP (PW)   14 | 94   TUBE             | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | -40 to 125   | 2737<br>MTC         |
| LM2737MTC/NOPB.A                | Active        | Production           | TSSOP (PW)   14 | 94   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2737<br>MTC         |
| LM2737MTC/NOPB.B                | Active        | Production           | TSSOP (PW)   14 | 94   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2737<br>MTC         |
| <a href="#">LM2737MTCX/NOPB</a> | Active        | Production           | TSSOP (PW)   14 | 2500   LARGE T&R      | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | -40 to 125   | 2737<br>MTC         |
| LM2737MTCX/NOPB.A               | Active        | Production           | TSSOP (PW)   14 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2737<br>MTC         |
| LM2737MTCX/NOPB.B               | Active        | Production           | TSSOP (PW)   14 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2737<br>MTC         |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

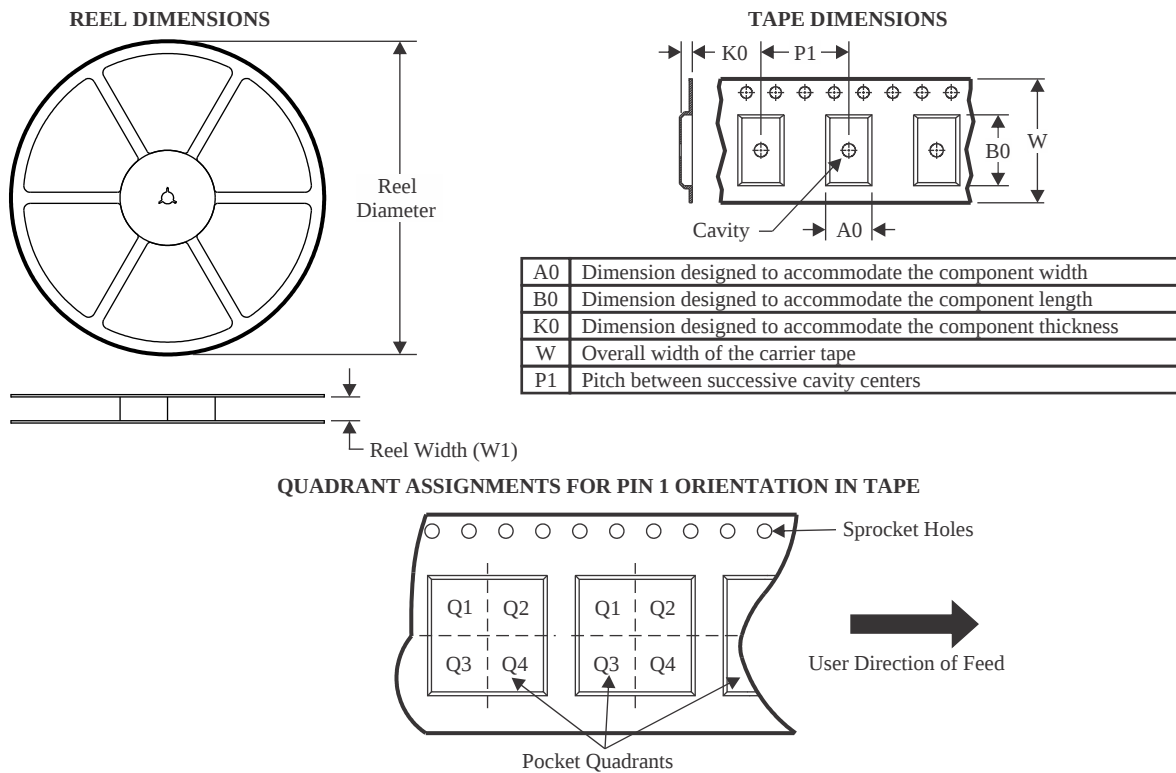
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

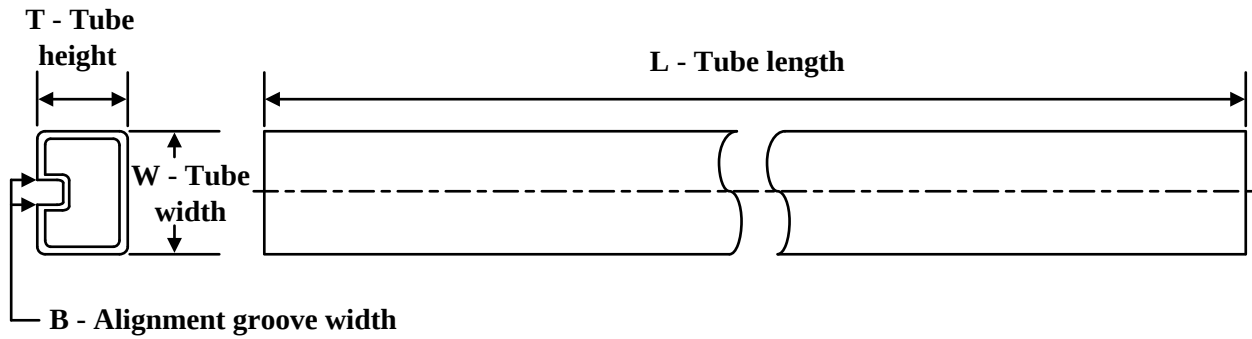
| Device          | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM2727MTCX/NOPB | TSSOP        | PW              | 14   | 2500 | 330.0              | 12.4               | 6.95    | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| LM2737MTCX/NOPB | TSSOP        | PW              | 14   | 2500 | 330.0              | 12.4               | 6.95    | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



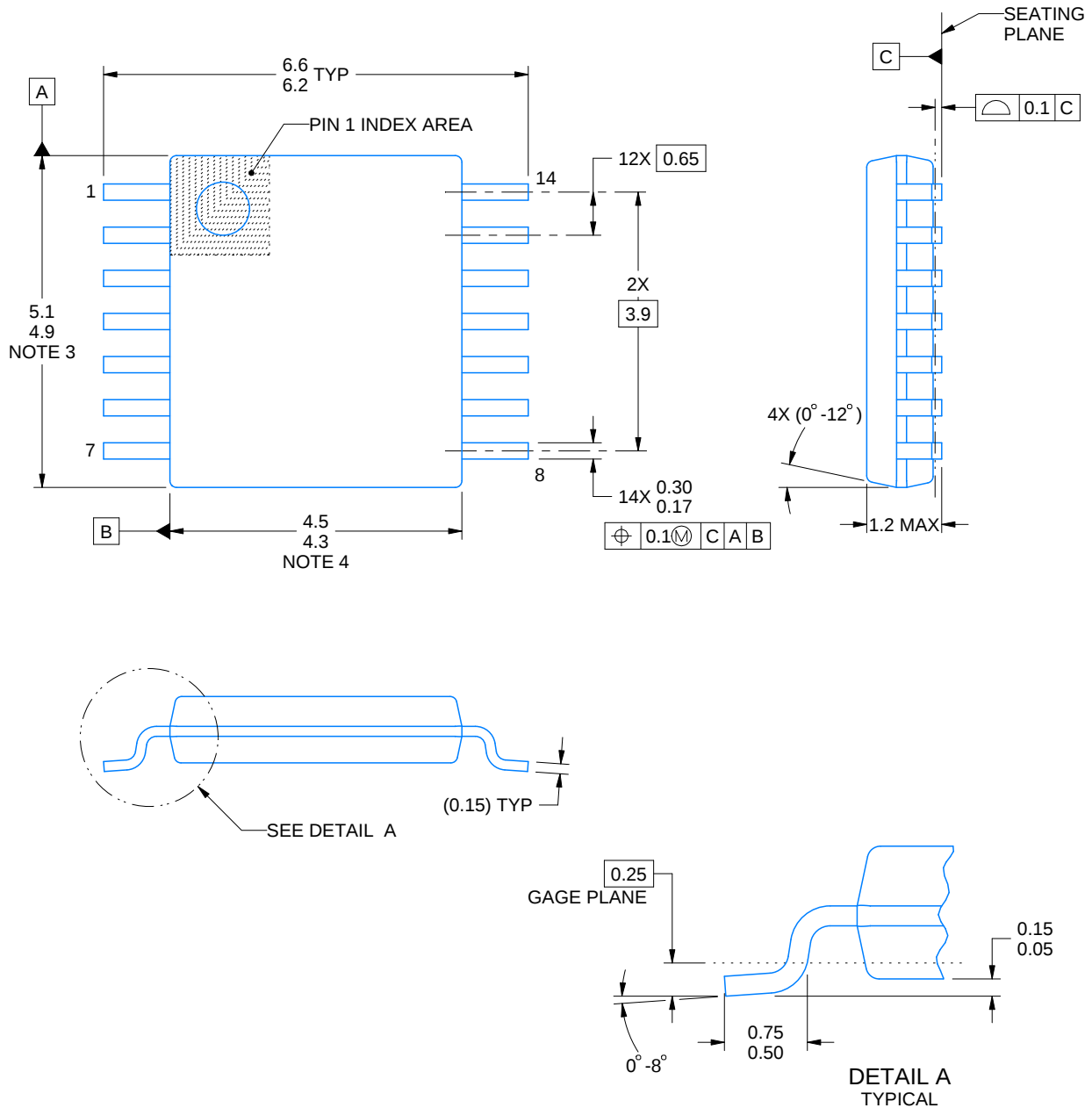
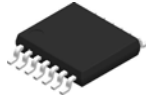
\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM2727MTCX/NOPB | TSSOP        | PW              | 14   | 2500 | 367.0       | 367.0      | 35.0        |
| LM2737MTCX/NOPB | TSSOP        | PW              | 14   | 2500 | 367.0       | 367.0      | 35.0        |

**TUBE**


\*All dimensions are nominal

| Device           | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LM2727MTC/NOPB   | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |
| LM2727MTC/NOPB   | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LM2727MTC/NOPB.B | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LM2727MTC/NOPB.B | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |
| LM2737MTC/NOPB   | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |
| LM2737MTC/NOPB   | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LM2737MTC/NOPB.A | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |
| LM2737MTC/NOPB.A | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LM2737MTC/NOPB.B | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LM2737MTC/NOPB.B | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |



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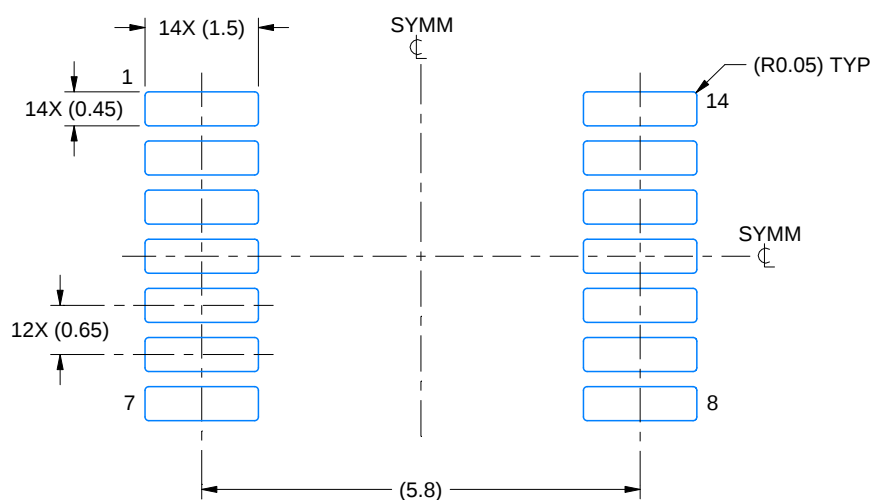
## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

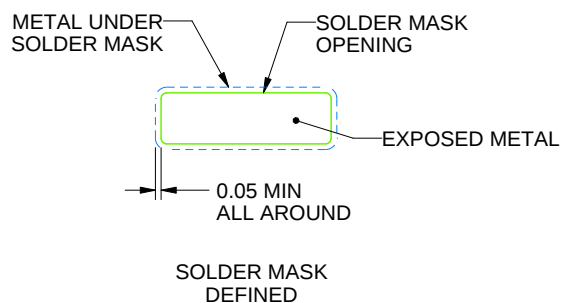
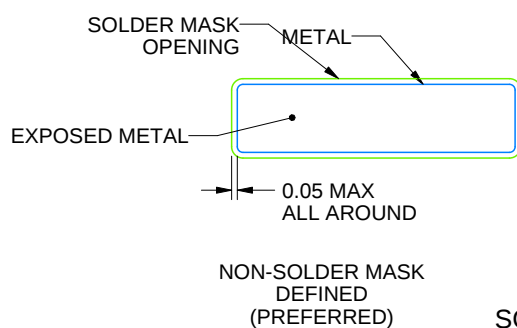
**PW0014A**

**TSSOP - 1.2 mm max height**

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



## SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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